NSN 5961-00-553-9220

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Inclosure Material:

Glass and metal

Overall Length:

Between 0.240 inches and 0.260 inches

Terminal Length:

0.500 inches

Overall Diameter:

Between 0.335 inches and 0.370 inches

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-5

Mounting Method:

Terminal

Terminal Circle Diameter:

0.200 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

25.0 collector to emitter voltage, dc with specified circuit between base and emitter and 30.0 collector to emitter voltage/static/base open

and 5.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

500.00 milliamperes source cutoff current and 100.00 milliamperes zero-gate-voltage source current absolute

Power Rating Per Characteristic:

1.0 watts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Test Data Document:

90536-7902633 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0